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# ISL9V5045S3S / ISL9V5045S3 EcoSPARK® N-Channel Ignition IGBT

500mJ, 450V

## Features

- SCIS Energy = 500mJ at  $T_J = 25^\circ\text{C}$
- Logic Level Gate Drive

## Applications

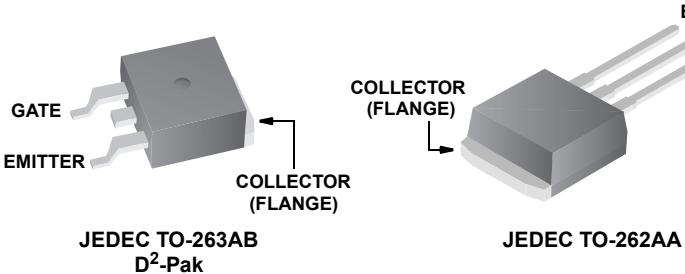
- Automotive Ignition Coil Driver Circuits
- Coil - On Plug Applications

## General Description

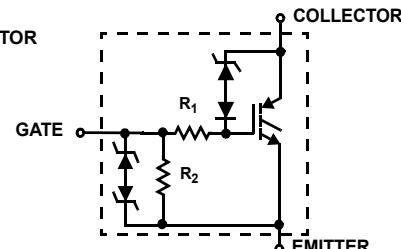
The ISL9V5045S3S and ISL9V5045S3 are next generation ignition IGBTs that offer outstanding SCIS capability in the industry standard D<sup>2</sup>-Pak (TO-263) plastic package. This device is intended for use in automotive ignition circuits, specifically as a coil drivers. Internal diodes provide voltage clamping without the need for external components.

EcoSPARK® devices can be custom made to specific clamp voltages. Contact your nearest Fairchild sales office for more information.

## Package



## Symbol



**Device Maximum Ratings**  $T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Ratings	Units
$BV_{CER}$	Collector to Emitter Breakdown Voltage ( $I_C = 1 \text{ mA}$ )	480	V
$BV_{ECS}$	Emitter to Collector Voltage - Reverse Battery Condition ( $I_C = 10 \text{ mA}$ )	24	V
$E_{SCIS25}$	At Starting $T_J = 25^\circ\text{C}$ , $I_{SCIS} = 39.2 \text{ A}$ , $L = 650 \mu\text{H}$	500	mJ
$E_{SCIS150}$	At Starting $T_J = 150^\circ\text{C}$ , $I_{SCIS} = 31.1 \text{ A}$ , $L = 650 \mu\text{H}$	315	mJ
$I_{C25}$	Collector Current Continuous, At $T_C = 25^\circ\text{C}$ , See Fig 9	51	A
$I_{C110}$	Collector Current Continuous, At $T_C = 110^\circ\text{C}$ , See Fig 9	43	A
$V_{GEM}$	Gate to Emitter Voltage Continuous	$\pm 10$	V
$P_D$	Power Dissipation Total $T_C = 25^\circ\text{C}$	300	W
	Power Dissipation Derating $T_C > 25^\circ\text{C}$	2	W/ $^\circ\text{C}$
$T_J$	Operating Junction Temperature Range	-40 to 175	$^\circ\text{C}$
$T_{STG}$	Storage Junction Temperature Range	-40 to 175	$^\circ\text{C}$
$T_L$	Max Lead Temp for Soldering (Leads at 1.6mm from Case for 10s)	300	$^\circ\text{C}$
$T_{pkg}$	Max Lead Temp for Soldering (Package Body for 10s)	260	$^\circ\text{C}$
ESD	Electrostatic Discharge Voltage at 100pF, 1500 $\Omega$	4	kV

**Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
V5045S	ISL9V5045S3ST	TO-263AB	330mm	24mm	800
V5045S	ISL9V5045S3	TO-262AA	Tube	N/A	50
V5045S	ISL9V5045S3S	TO-263AB	Tube	N/A	50

**Electrical Characteristics**  $T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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**Off State Characteristics**

$BV_{CER}$	Collector to Emitter Breakdown Voltage	$I_C = 2 \text{ mA}$ , $V_{GE} = 0$ , $R_G = 1 \text{ k}\Omega$ , See Fig. 15 $T_J = -40$ to $150^\circ\text{C}$	420	450	480	V
$BV_{CES}$	Collector to Emitter Breakdown Voltage	$I_C = 10 \text{ mA}$ , $V_{GE} = 0$ , $R_G = 0$ , See Fig. 15 $T_J = -40$ to $150^\circ\text{C}$	445	475	505	V
$BV_{ECS}$	Emitter to Collector Breakdown Voltage	$I_C = -75 \text{ mA}$ , $V_{GE} = 0 \text{ V}$ , $T_C = 25^\circ\text{C}$	30	-	-	V
$BV_{GES}$	Gate to Emitter Breakdown Voltage	$I_{GES} = \pm 2 \text{ mA}$	$\pm 12$	$\pm 14$	-	V
$I_{CER}$	Collector to Emitter Leakage Current	$V_{CER} = 320 \text{ V}$ , $T_C = 25^\circ\text{C}$ $R_G = 1 \text{ k}\Omega$ , See Fig. 11	-	-	25	$\mu\text{A}$
			$T_C = 150^\circ\text{C}$	-	1	mA
$I_{ECS}$	Emitter to Collector Leakage Current	$V_{EC} = 24 \text{ V}$ , See Fig. 11	$T_C = 25^\circ\text{C}$	-	1	mA
			$T_C = 150^\circ\text{C}$	-	40	mA
$R_1$	Series Gate Resistance		-	100	-	$\Omega$
$R_2$	Gate to Emitter Resistance		10K	-	30K	$\Omega$

**On State Characteristics**

$V_{CE(SAT)}$	Collector to Emitter Saturation Voltage	$I_C = 10 \text{ A}$ , $V_{GE} = 4.0 \text{ V}$	$T_C = 25^\circ\text{C}$ , See Fig. 4	-	1.25	1.60	V
$V_{CE(SAT)}$	Collector to Emitter Saturation Voltage	$I_C = 15 \text{ A}$ , $V_{GE} = 4.5 \text{ V}$	$T_C = 150^\circ\text{C}$	-	1.47	1.80	V

### Dynamic Characteristics

$Q_{G(ON)}$	Gate Charge	$I_C = 10A, V_{CE} = 12V, V_{GE} = 5V$ , See Fig. 14	-	32	-	nC
$V_{GE(TH)}$	Gate to Emitter Threshold Voltage	$I_C = 1.0mA, V_{CE} = V_{GE}$ , See Fig. 10	$T_C = 25^\circ C$	1.3	-	2.2
			$T_C = 150^\circ C$	0.75	-	1.8
$V_{GEP}$	Gate to Emitter Plateau Voltage	$I_C = 10A, V_{CE} = 12V$	-	3.0	-	V

### Switching Characteristics

$t_{d(ON)R}$	Current Turn-On Delay Time-Resistive	$V_{CE} = 14V, R_L = 1\Omega, V_{GE} = 5V, R_G = 1K\Omega, T_J = 25^\circ C$ , See Fig. 12	-	0.7	4	$\mu s$
$t_{rR}$	Current Rise Time-Resistive		-	2.1	7	$\mu s$
			-	2.8	15	$\mu s$
$t_{d(OFF)L}$	Current Turn-Off Delay Time-Inductive	$V_{CE} = 300V, L = 2mH, V_{GE} = 5V, R_G = 1K\Omega, T_J = 25^\circ C$ , See Fig. 12	-	10.8	15	$\mu s$
			-	2.8	15	$\mu s$
SCIS	Self Clamped Inductive Switching	$T_J = 25^\circ C, L = 650\ \mu H, R_G = 1K\Omega, V_{GE} = 5V$ , See Fig. 1 & 2	-	-	500	mJ

### Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction-Case	TO-263, TO-262	-	-	0.5	$^\circ C/W$
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### Typical Characteristics

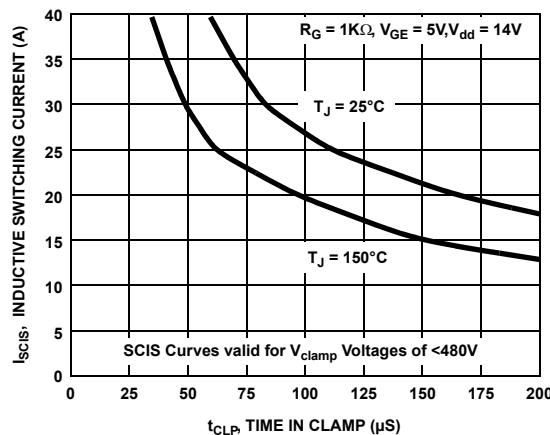


Figure 1. Self Clamped Inductive Switching Current vs Time in Clamp

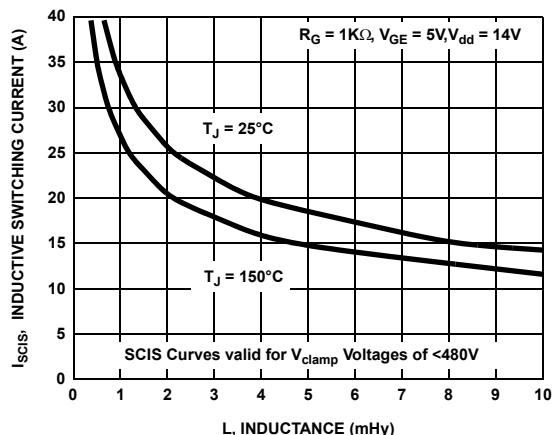
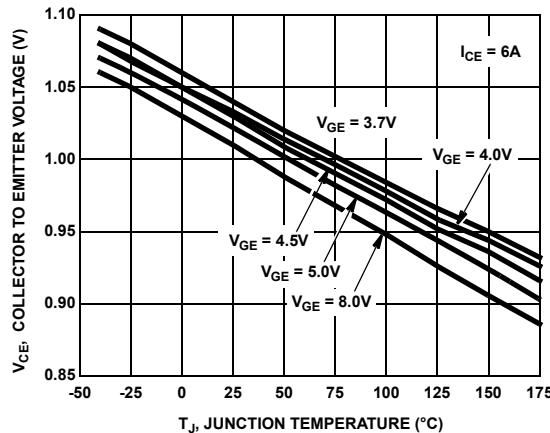
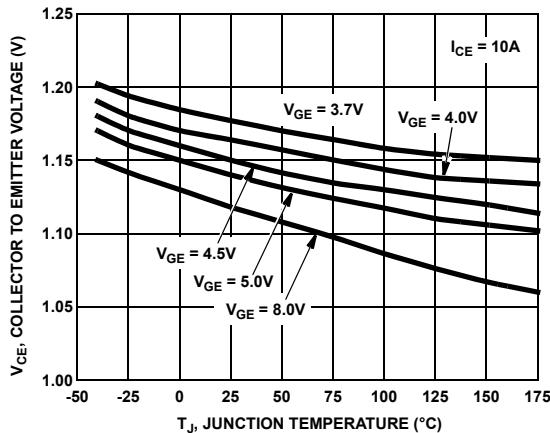


Figure 2. Self Clamped Inductive Switching Current vs Inductance

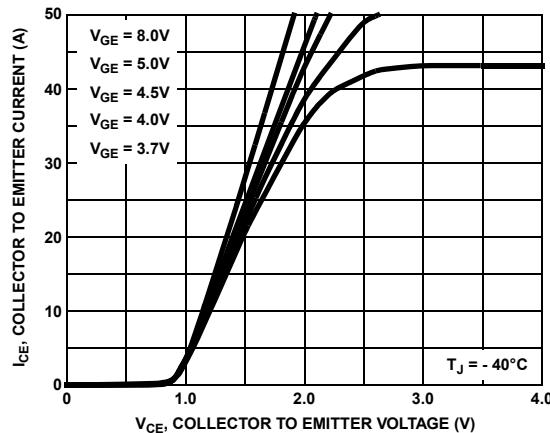
**Typical Characteristics (Continued)**



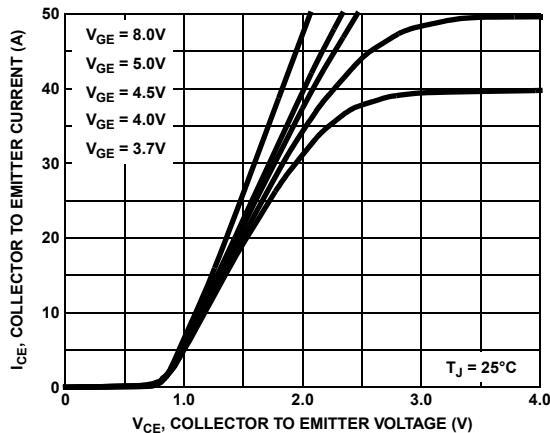
**Figure 3. Collector to Emitter On-State Voltage vs Junction Temperature**



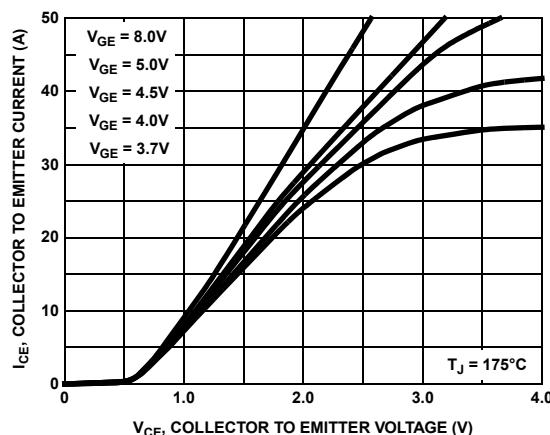
**Figure 4. Collector to Emitter On-State Voltage vs Junction Temperature**



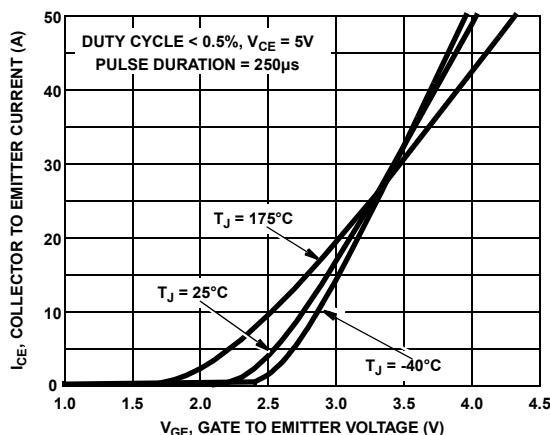
**Figure 5. Collector Current vs Collector to Emitter On-State Voltage**



**Figure 6. Collector Current vs Collector to Emitter On-State Voltage**

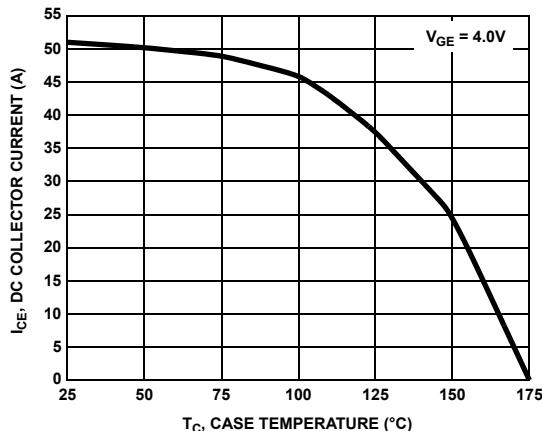


**Figure 7. Collector to Emitter On-State Voltage vs Collector Current**

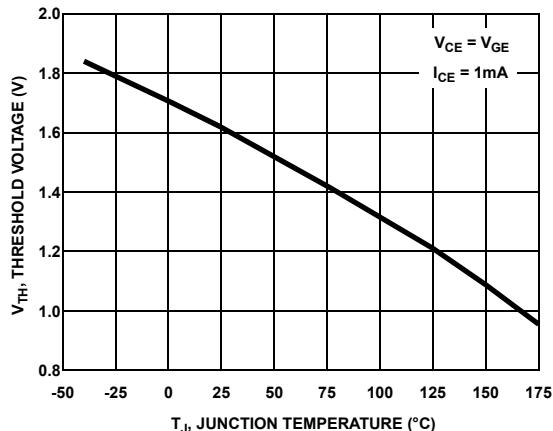


**Figure 8. Transfer Characteristics**

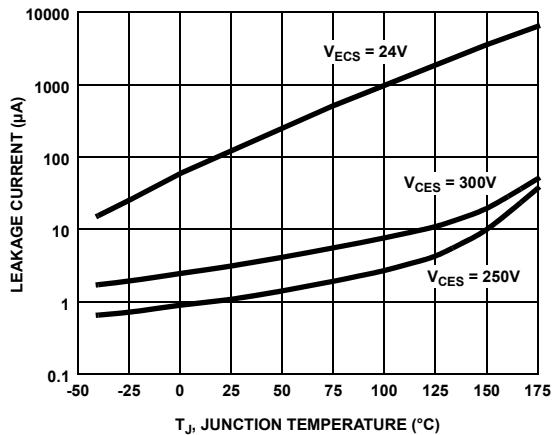
**Typical Characteristics (Continued)**



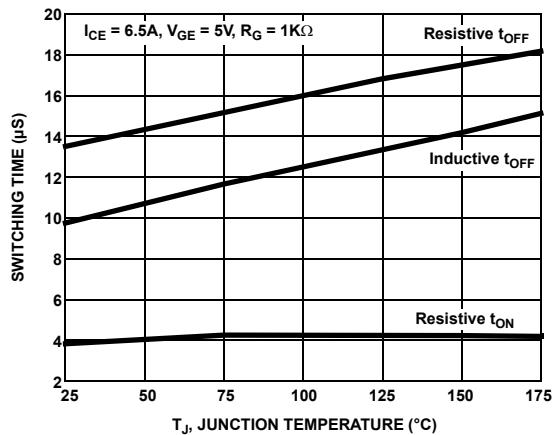
**Figure 9. DC Collector Current vs Case Temperature**



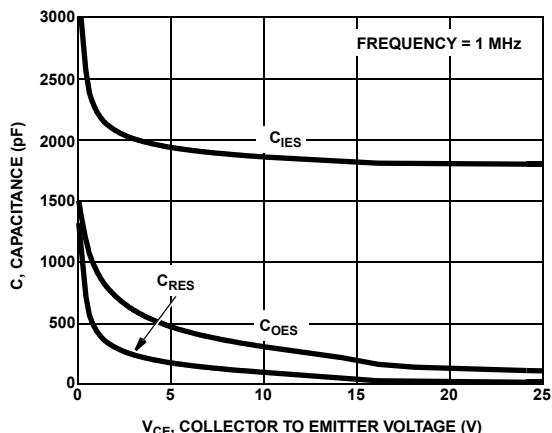
**Figure 10. Threshold Voltage vs Junction Temperature**



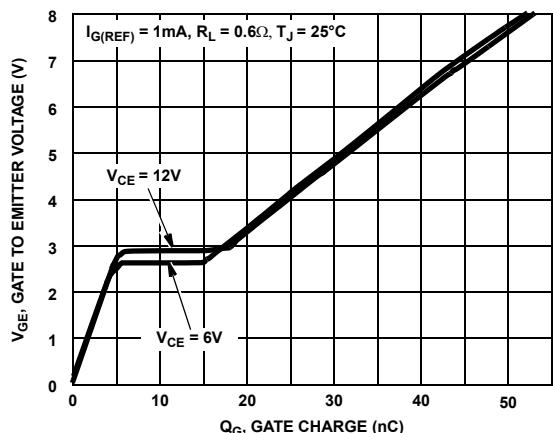
**Figure 11. Leakage Current vs Junction Temperature**



**Figure 12. Switching Time vs Junction Temperature**



**Figure 13. Capacitance vs Collector to Emitter Voltage**



**Figure 14. Gate Charge**

Typical Characteristics (Continued)

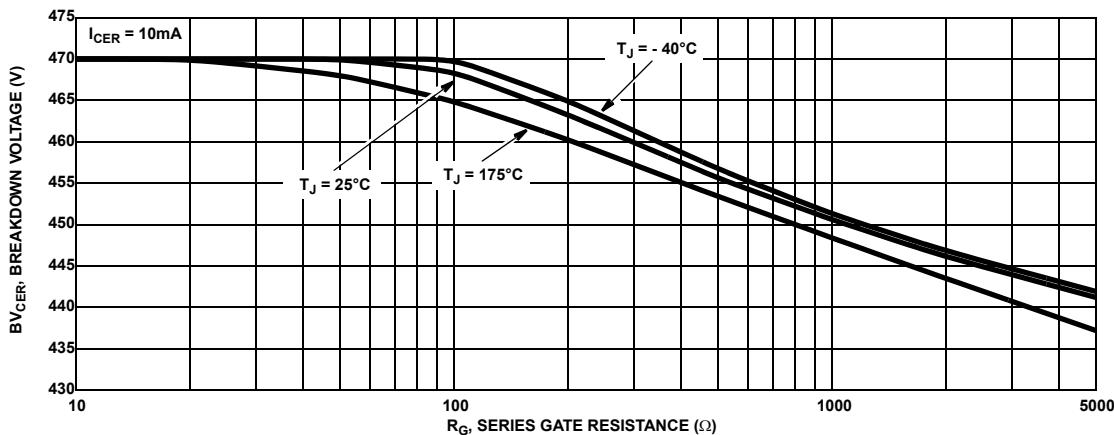


Figure 15. Breakdown Voltage vs Series Gate Resistance

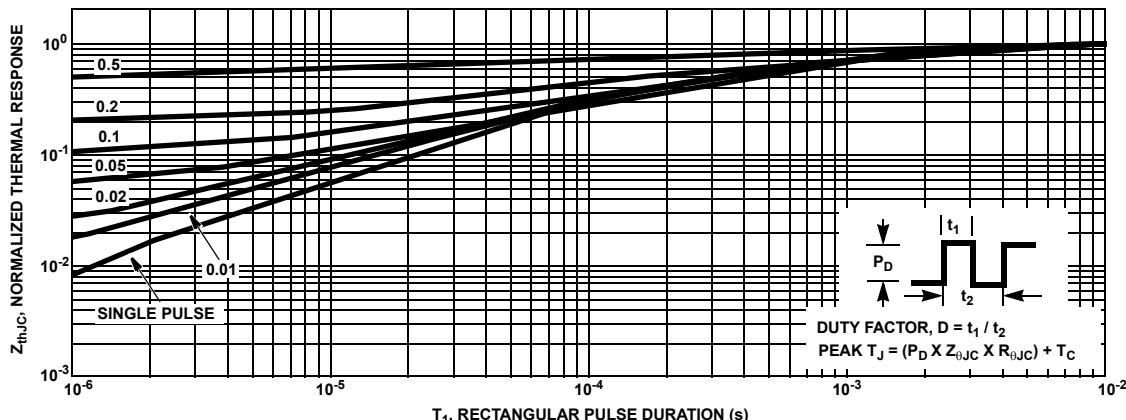


Figure 16. IGBT Normalized Transient Thermal Impedance, Junction to Case

Test Circuits and Waveforms

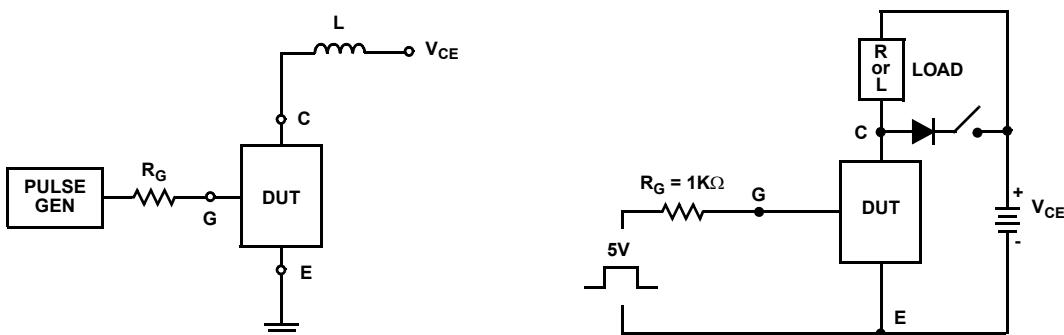


Figure 17. Inductive Switching Test Circuit

Figure 18.  $t_{ON}$  and  $t_{OFF}$  Switching Test Circuit

**Test Circuits and Waveforms (Continued)**

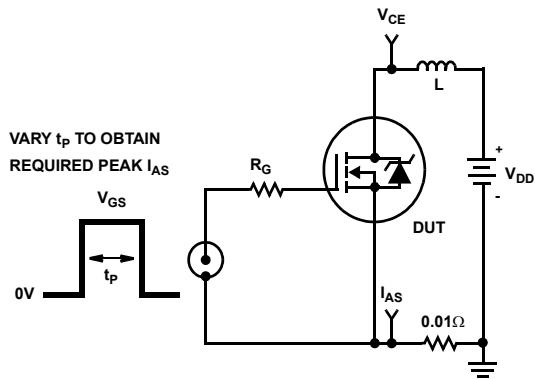


Figure 19. Energy Test Circuit

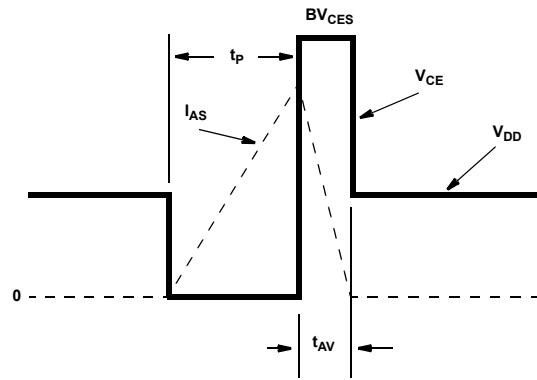


Figure 20. Energy Waveforms

## SPICE Thermal Model

REV 27 May 2005

ISL9V5045S3S / ISL9V5045S3

```
CTHERM1 th 6 82e-4
CTHERM2 6 5 105e-4
CTHERM3 5 4 12e-3
CTHERM4 4 3 33e-3
CTHERM5 3 2 55e-3
CTHERM6 2 tl 170e-3
```

```
RTHERM1 th 6 3e-3
RTHERM2 6 5 20e-3
RTHERM3 5 4 50e-3
RTHERM4 4 3 60e-3
RTHERM5 3 2 100e-3
RTHERM6 2 tl 127e-3
```

## SABER Thermal Model

SABER thermal model

ISL9V5045S3S / ISL9V5045S3

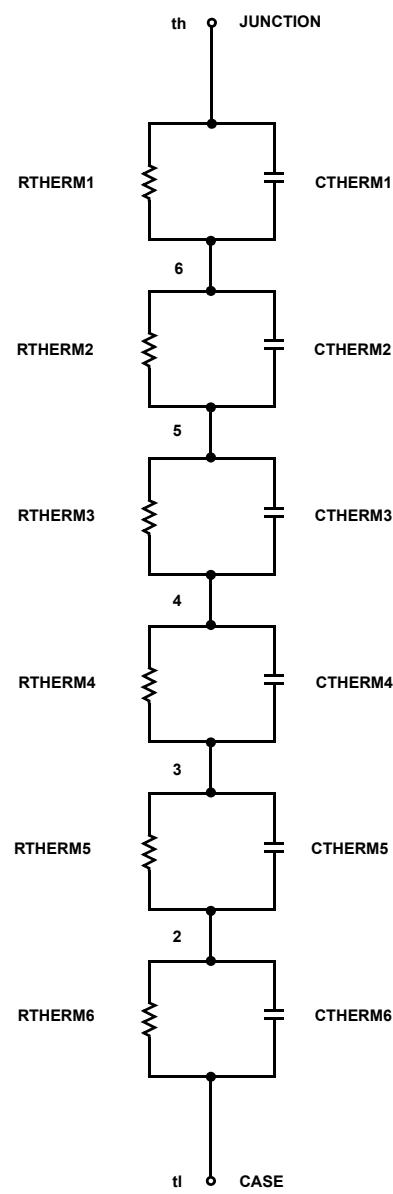
template thermal\_model th tl

thermal\_c th, tl

{

```
ctherm.ctherm1 th 6 = 82e-4
ctherm.ctherm2 6 5 = 105e-4
ctherm.ctherm3 5 4 = 12e-3
ctherm.ctherm4 4 3 = 33e-3
ctherm.ctherm5 3 2 = 55e-3
ctherm.ctherm6 2 tl = 170e-3
```

```
rtherm.rtherm1 th 6 = 3e-3
rtherm.rtherm2 6 5 = 20e-3
rtherm.rtherm3 5 4 = 50e-3
rtherm.rtherm4 4 3 = 60e-3
rtherm.rtherm5 3 2 = 100e-3
rtherm.rtherm6 2 tl = 127e-3
}
```





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В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибуторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ Р В 0015-002 и ЭС РД 009

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